# **74AUP1G16**

### Low-power buffer Rev. 5 — 17 July 2023

17 July 2023 Product data sheet

### 1. General description

The 74AUP1G16 provides a low-power, low-voltage single buffer.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- · Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- · Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package									
	Temperature range	Name	Description	Version						
74AUP1G16GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1						
74AUP1G16GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886						



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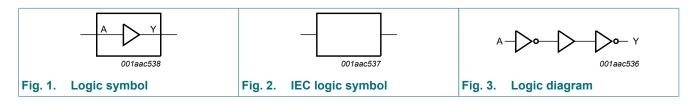
## 4. Marking

#### Table 2. Marking

Type number	Marking code [1]
74AUP1G16GW	5N
74AUP1G16GM	5N

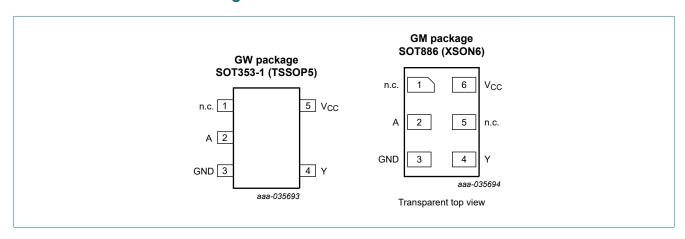
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram



## 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description	
	TSSOP5	XSON6	
n.c.	1	1	not connected
A	2	2	data input
GND	3	3	ground (0 V)
Υ	4	4	data output
n.c.	-	5	not connected
V <sub>CC</sub>	5	6	supply voltage

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## 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input	Output
A	Υ
L	L
Н	Н

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [2]	-	250	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	0	200	ns/V

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<sup>[2]</sup> For SOT353-1 (TSSOP5) package: P<sub>tot</sub> derates linearly with 3.3 mW/K above 74 °C.

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

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## 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	25 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0 V$ to 3.6 V; $V_{CC} = 0 V$	-	-	±0.2	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μΑ
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_{I}$ = GND or $V_{CC}$	-	8.0	-	pF
Co	output capacitance	V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.7	-	pF

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	_	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	_	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	_	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	_	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
I	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μΑ
OFF	power-off leakage current	$V_{I}$ or $V_{O} = 0 V$ to 3.6 V; $V_{CC} = 0 V$	-	-	±0.5	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.6	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.9	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μΑ

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +125 °C					•
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.75 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.25 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.40	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
ı	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.75	μΑ
OFF	power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.75	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.75	μΑ
lcc	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	75	μΑ

<sup>[1]</sup> One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND.

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# 11. Dynamic characteristics

### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5.

Symbol	Parameter	Conditions	T	<sub>amb</sub> = 25	°C	T <sub>an</sub>	<sub>nb</sub> = o +85 °C	T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F		'							
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 4</u> [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	15.0	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.6	4.7	9.2	2.0	10.0	2.0	11.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.1	3.4	5.7	1.6	6.5	1.6	7.2	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.8	2.9	4.5	1.4	5.2	1.4	5.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.5	2.3	3.5	1.2	4.2	1.2	4.6	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.4	2.1	3.2	1.0	3.8	1.0	4.2	ns
C <sub>L</sub> = 10	pF		'							
t <sub>pd</sub>	propagation	A to Y; see Fig. 4 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	18.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.2	5.6	10.9	2.3	11.8	2.3	13.1	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.6	4.1	6.7	1.9	7.7	1.9	8.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	3.4	5.3	1.7	6.2	1.7	6.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.0	2.9	4.2	1.5	5.0	1.5	5.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	2.6	3.8	1.4	4.6	1.4	5.1	ns
C <sub>L</sub> = 15	pF				•					
t <sub>pd</sub>	propagation	A to Y; see Fig. 4 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	21.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	6.4	12.6	2.6	13.8	2.6	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	4.6	7.6	2.2	8.9	2.2	9.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.6	3.9	6.0	2.0	7.2	2.0	7.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.3	3.3	4.8	1.8	5.7	1.8	6.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.1	3.1	4.2	1.6	5.0	1.6	5.5	ns
C <sub>L</sub> = 30	pF									
t <sub>pd</sub>	propagation	A to Y; see Fig. 4 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	32.1	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.8	8.7	16.3	3.6	18.9	3.6	20.8	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.0	6.2	10.3	3.4	12.2	3.4	13.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.6	5.2	8.1	3.2	9.8	3.2	10.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.0	4.4	6.4	2.7	7.7	2.7	8.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.9	4.2	5.6	2.5	6.5	2.5	7.2	ns

#### Low-power buffer

Symbol	Parameter Conditions		Ta	<sub>amb</sub> = 25 °	°C	T <sub>am</sub> -40 °C to	<sub>nb</sub> = o +85 °C	T <sub>an</sub> -40 °C to	<sub>nb</sub> = +125 °C	Unit		
			Min	Typ [1]	Max	Min	Max	Min	Max			
C <sub>PD</sub>	power	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3]										
	dissipation capacitance	•	•	V <sub>CC</sub> = 0.8 V	-	2.5	-	-	-	-	-	pF
			V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.6	-	-	-	-	-	pF	
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	2.7	-	-	-	-	-	pF		
	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	V <sub>CC</sub> = 1.65 V to 1.95 V	-	2.9	-	-	-	-	-	pF		
		-	3.4	-	-	-	-	-	pF			
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.0	-	-	-	-	-	pF		

- All typical values are measured at nominal  $V_{\text{CC}}$ .
- $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

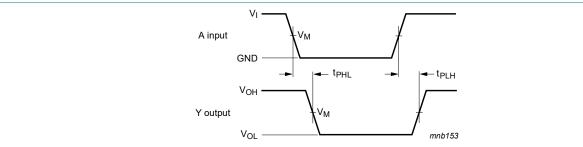
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

### 11.1. Waveforms and test circuit



Measurement points are given in Table 9.

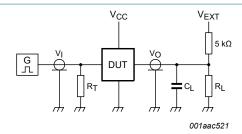
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 4. The data input (A) to output (Y) propagation delays

**Table 9. Measurement points** 

Supply voltage	Output			
V <sub>CC</sub>	V <sub>M</sub>	VI	$t_r = t_f$	V <sub>M</sub>
0.8 V to 3.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>

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Test data is given in Table 10.

Definitions for test circuit:

R<sub>L</sub> = Load resistance;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator;

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

### Fig. 5. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Load		V <sub>EXT</sub>		
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L$  = 5 k $\Omega$ . For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1 M $\Omega$ .

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# 12. Package outline

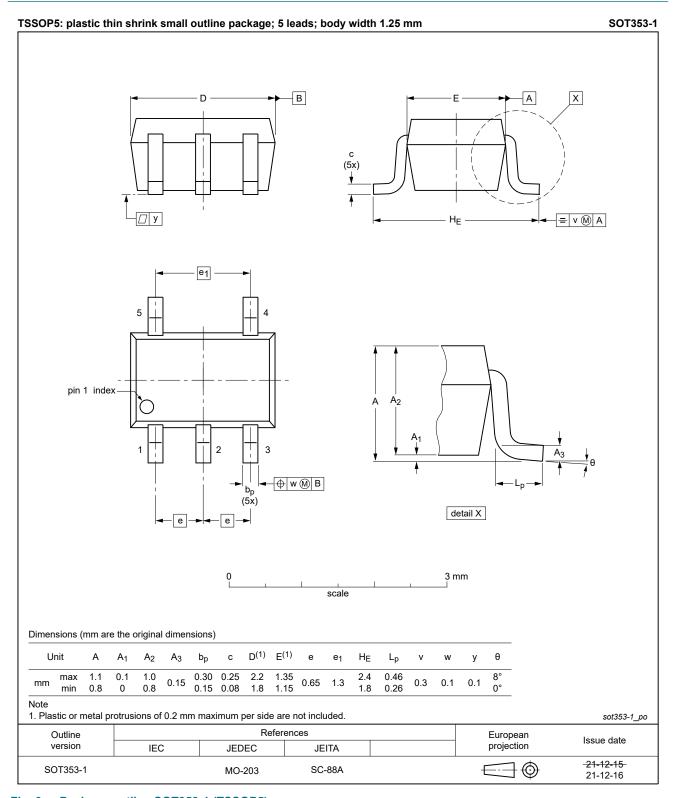


Fig. 6. Package outline SOT353-1 (TSSOP5)

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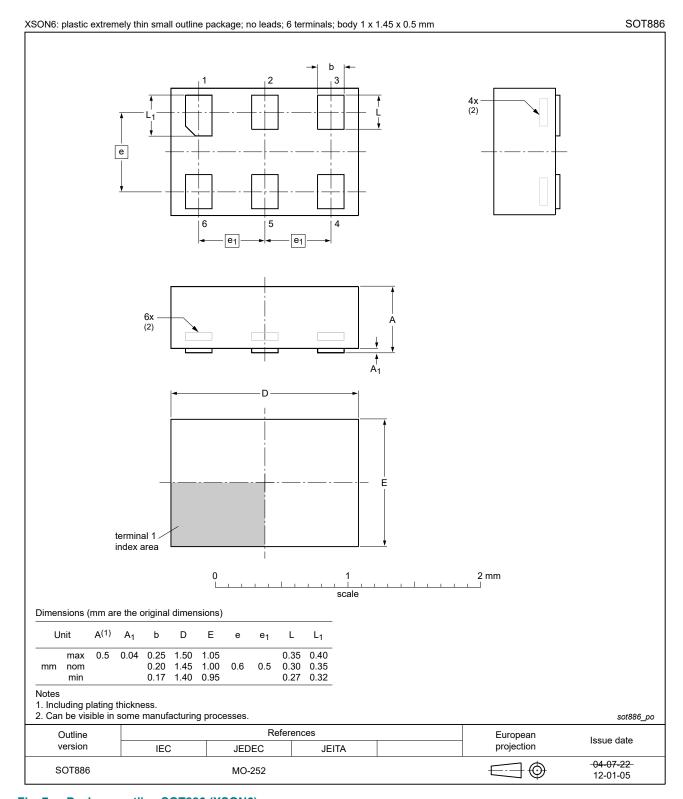


Fig. 7. Package outline SOT886 (XSON6)

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### 13. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

# 14. Revision history

### **Table 12. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AUP1G16 v.5	20230717	Product data sheet	-	74AUP1G16 v.4	
Modifications:	Section 2: I	<u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.			
74AUP1G16 v.4	20220118	Product data sheet	-	74AUP1G16 v.3	
Modifications:	• <u>Fig. 6</u> : Pacl	kage outline drawing for SC	T353-1 (TSSOP5	i) has changed.	
74AUP1G16 v.3	20201027	Product data sheet	-	74AUP1G16 v.2	
Modifications:	guidelines of Legal texts Type numb	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type number 74AUP1G16GF (SOT891 / XSON6) removed.</li> <li>Table 5: Derating values for Ptot total power dissipation updated.</li> </ul>			
74AUP1G16 v.2	20161007	Product data sheet	-	74AUP1G16 v.1	
Modifications:	Type numb	Type numbers 74AUP1G16GN, 74AUP1G16GS and 74AUP1G16GX removed.			
74AUP1G16 v.1	20151104	Product data sheet	-	-	

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### 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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